

## The $A1B_2$ Structure in the $EuM_xSi_{2-x}$ System

I. MAYER AND I. FELNER

*Department of Inorganic and Analytical Chemistry, Hebrew University, Jerusalem, Israel*

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The  $A1B_2$  type hexagonal structure was studied in the  $EuM_xSi_{2-x}$  system, for  $M = Fe, Co, Ni, Cu, Ag$  and  $Au$ . Only  $EuCu_{0.5}Si_{1.5}$  and  $EuAg_{0.67}Si_{1.33}$  crystallize as single phases. The Mössbauer spectrum of  $EuCu_{0.5}Si_{1.5}$  shows europium to be divalent. Valence electron concentration and packing of the layers in the  $LnCu_xSi_{2-x}$  and  $LnAg_xSi_{2-x}$  systems is discussed. Higher stability of the  $EuCu_xSi_{2-x}$  and  $EuAg_xSi_{2-x}$  compounds is explained by the close similarity in size of  $Cu$  and  $Ag$  to  $Si$ .

Ternary rare earth silicides crystallizing in the  $A1B_2$ -type hexagonal structure, have been reported previously (1-3). The  $A1B_2$  type structure is built up from layers of the nonmetals with the metals interspersed. In the ternary rare earth silicides part of the silicon in the hexagon-like layers is replaced by transition metals. The close packing in the ternary compounds depends on the penetration of the rare earth atoms into the silicon layers.

The present work deals with compounds of the  $EuM_xSi_{2-x}$  system ( $M = Fe, Co, Ni, Cu, Ag$  and  $Au$ ) having the  $A1B_2$  type hexagonal structure. Some of the compounds were first observed as second phases in our studies of the  $ThCr_2Si_2$  type silicides (4, 5); these have now been prepared as single phases.

### Experimental

The compounds were prepared by melting together europium, the transition metals and silicon (all of 99.9% purity) in alumina crucibles in an induction furnace under a protective atmosphere of argon. They were X-ray analyzed by a Philips Diffractometer using Ni-filtered  $CuK\alpha$  radiation. Mössbauer effect measurement has been carried out using 22 keV  $\gamma$  rays of  $^{151}Eu$  isotope. The  $\gamma$  rays were obtained from a  $^{151}Sm$  source in the form of  $Sm_2O_3$ .

### Results and Discussion

In Table I, cell dimensions of the  $A1B_2$  type  $EuM_xSi_{2-x}$  compounds are listed. The  $A1B_2$  type structure was not observed in the  $EuFe_xSi_{2-x}$  system.  $EuCu_{0.5}Si_{1.5}$  and  $EuAg_{0.67}Si_{1.33}$  crystallize as pure  $A1B_2$ -type phases, but when the metal content was increased, the  $ThCr_2Si_2$ -type structure appeared as a second phase. None of the  $Co, Ni,$  and  $Au$  compounds could be obtained as single phases.

In Fig. 1 the Mössbauer spectrum of  $Eu$  in  $EuCu_{0.5}Si_{1.5}$  is shown. The isomer shift found relative to  $Eu_2O_3$  is  $-11 \pm 0.2$  mm/sec, which is the isomer shift found for divalent europium in metallic compounds (6).

In Table II lattice constants of  $EuCu_{0.5}Si_{1.5}$

TABLE I  
LATTICE CONSTANTS OF HEXAGONAL  $A1B_2$ -TYPE  
 $EuM_xSi_{2-x}$  COMPOUNDS

	$a$ (Å)	$c$ (Å)
$EuCo_{0.5}Si_{1.5}$	4.046	4.500
$EuNi_{0.5}Si_{1.5}$	4.034	4.496
$EuCu_{0.5}Si_{1.5}$	4.080	4.466
$EuAg_{0.67}Si_{1.33}$	4.203	4.465
$EuAu_{0.5}Si_{1.5}$	4.150	4.515

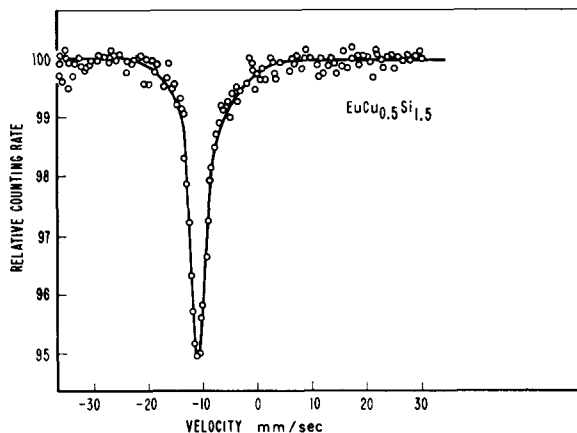


FIG. 1. Mössbauer spectrum of Eu in  $\text{EuCu}_{0.5}\text{Si}_{1.5}$ .

and  $\text{EuAg}_{0.67}\text{Si}_{1.33}$  are compared with the lattice parameters of the corresponding compounds of the other rare earth metals. This comparison shows significant increase in  $c$  of the Eu-compounds, while  $a$  changes less sharply. Assuming that europium is divalent in the  $\text{AlB}_2$  type  $\text{EuM}_x\text{Si}_{2-x}$  compounds, as is found for  $\text{EuCu}_{0.5}\text{Si}_{1.5}$ , the valence electron concentration in the Eu-compounds is decreasing and consequently the bonds in the graphitic layers will become weaker. The  $\text{AlB}_2$  structure forms therefore at lower Ag content than in the case of the other relatively big rare earth metals (3). The effective space in the hexagons is, however, still small for efficient penetration of the relatively large europium atoms. The packing between the metallic and nonmetallic layers will be therefore less dense and  $c$ , which represents the distance

between the layers of the Eu atoms, must increase.

The mean radii of the nonmetals in the  $\text{AlB}_2$  structure and the transition metals substituting part of them, equals to a good approximation to  $a/\sqrt{3}$ . The size of the transition metals in the different  $\text{EuM}_x\text{Si}_{2-x}$  compounds will be in the order of these mean radii, namely  $\text{Co} < \text{Ni} < \text{Cu} < \text{Si} < \text{Ag} < \text{Au}$ . The radii of Cu and Ag are closest to that of Si, hence these atoms form most easily  $\text{AlB}_2$  type compounds. In the case of Co, Ni and Au the  $\text{AlB}_2$  type phase appears with additional phases.

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TABLE II

LATTICE CONSTANTS AND VALENCE ELECTRON CONCENTRATION (VEC) OF HEXAGONAL ( $P6/mmm$ )  $\text{AlB}_2$ -TYPE  $\text{LnCu}_x\text{Si}_{2-x}$  AND  $\text{LnAg}_x\text{Si}_{2-x}$  COMPOUNDS

	$a$ (Å)	$c$ (Å)	$vec$
$\text{EuCu}_{0.5}\text{Si}_{1.5}$	4.080	4.496	2.833
$\text{LaCu}_{0.5}\text{Si}_{1.5}^a$	4.144	4.286	3.166
$\text{CeCu}_{0.5}\text{Si}_{1.5}^a$	4.136	4.237	3.166
$\text{EuAg}_{0.67}\text{Si}_{1.33}$	4.203	4.465	2.666
$\text{DyAg}_{0.67}\text{Si}_{1.33}$	4.133	4.036	3.000
$\text{ErAg}_{0.67}\text{Si}_{1.33}$	4.196	4.095	3.000

<sup>a</sup> From Ref. (1).

#### References

1. W. RIEGER AND E. PARTHE, *Monatsh. Chem.* **100**, 439 (1969).
2. I. MAYER AND M. TASSA, *J. Less Common Metals* **19**, 173 (1969).
3. I. MAYER AND I. FELNER, *J. Solid State Chem.* (in press).
4. I. MAYER AND J. COHEN, *J. Less Common Metals* **29**, 221 (1972).
5. I. MAYER, J. COHEN, AND I. FELNER, Collected Abstracts, Ninth Intern. Congress Cryst., Kyoto, Japan, p. S. 102 (1972).
6. H. H. WICKMAN, I. NOWIK, J. H. WERNICK, D. A. SHIRLEY, AND R. B. FRANKEL, *J. Appl. Phys.* **37**, 1246 (1966).